

9097250 TOSHIBA (DISCRETE/OPTO)

56C 07693

D T-33-09

2SC3310

SILICON NPN TRIPLE DIFFUSED TYPE

SWITCHING REGULATOR AND HIGH VOLTAGE SWITCHING
APPLICATIONS:
HIGH SPEED DC-DC CONVERTER APPLICATION.

FEATURES:

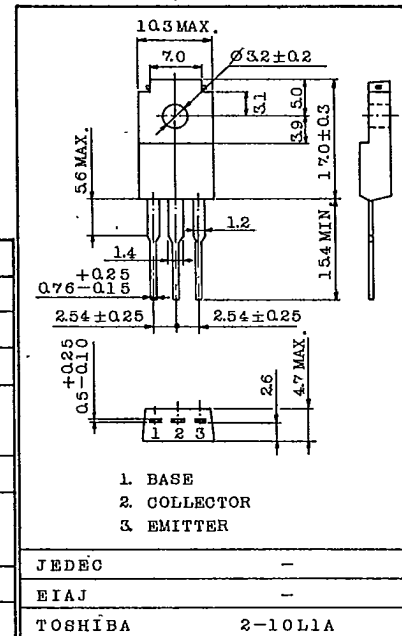
- Excellent Switching Times
: $t_r=1.0\mu s$ (Max.), $t_f=1.0\mu s$ (Max.) at $I_C=4A$
- High Collector Breakdown Voltage : $V_{CEO}=400V$

MAXIMUM RATINGS ($T_a=25^\circ C$)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Collector-Base Voltage		V_{CBO}	500	V
Collector-Emitter Voltage		V_{CEO}	400	V
Emitter-Base Voltage		V_{EBO}	7	V
Collector Current	DC	I_C	5	A
	Pulse	I_{CP}	7	A
Base Current		I_B	1	A
Collector Power Dissipation	$T_a=25^\circ C$	P_C	2.0	W
	$T_c=25^\circ C$		30	
Junction Temperature		T_j	150	$^\circ C$
Storage Temperature Range		T_{stg}	-55~150	$^\circ C$

INDUSTRIAL APPLICATIONS

Unit in mm



Weight : 2.1g

ELECTRICAL CHARACTERISTICS ($T_a=25^\circ C$)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current		I_{CBO}	$V_{CB}=400V, I_E=0$	-	-	100	μA
Emitter Cut-off Current		I_{EBO}	$V_{EB}=7V, I_C=0$	-	-	1	mA
Collector-Base Breakdown Voltage		$V(BR)_{CBO}$	$I_C=1mA, I_E=0$	500	-	-	V
Collector-Emitter Breakdown Voltage		$V(BR)_{CEO}$	$I_C=10mA, I_B=0$	400	-	-	V
DC Current Gain		h_{FE}	$V_{CE}=5V, I_C=3A$	12	-	-	
			$V_{CE}=5V, I_C=5A$	8	-	-	
Collector-Emitter Saturation Voltage		$V_{CE(sat)}$	$I_C=5A, I_B=1A$	-	-	1.0	V
Base-Emitter Saturation Voltage		$V_{BE(sat)}$	$I_C=5A, I_B=1A$	-	-	1.5	V
Switching Time	Rise Time	t_r		-	-	1.0	μs
	Storage Time	t_{stg}		-	-	2.5	
	Fall Time	t_f		-	-	1.0	

TOSHIBA CORPORATION